


ROITHNER LASERTECHNIK GmbH

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 1040 VIENNA
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SMB1N-1150D

- Infrared High Power LED
- 1150 nm, 210 mW
- InGaAsP chip, 1000 x 1000 µm
- PA9T SMD package
- Beam Angle: ± 64°



Description

SMB1N-1150D is a surface mount InGaAsP based high power infrared LED, with a typical peak wavelength of 1150 nm and optical output power of 210 mW @ 1 A. It comes in polyamide resin SMD package (PA9T) with silver plated soldering pads (lead free solderable), copper heat sink, and silicone resin mold. Additional variants with different beam angles are available on request.

Maximum Ratings*

Parameter	Symbol	Values		Unit
		Min.	Max.	
Power Dissipation	P_D		3600	mW
Forward Current	I_F		1500	mA
Pulse Forward Current **	I_{FP}		4000	mA
Reverse Voltage	U_R		5	V
Reverse Current ($U_R = 5V$)	I_R		10	µA
Thermal Resistance	R_{THJA}		10	K/W
Junction Temperature	T_J		120	°C
Operating Temperature	T_{CASE}	- 40	+ 100	°C
Storage Temperature	T_{STG}	- 40	+ 100	°C
Lead Solder Temperature ($t_{max.} 5s$)	T_{SLD}		+ 250	°C

* Operating close to or exceeding these parameters may damage the device

** duty cycle = 1 %, pulse width = 10 µs

Electro-Optical Characteristics ($T_{CASE} = 25^\circ C$)

Parameter	Symbol	Conditions	Min.	Values		Unit
				Typ.	Max.	
Peak Wavelength	λ_P	$I_F=1 A$	1100		1200	nm
Half Width	λ_Δ	$I_F=1 A$		70		nm
Forward Voltage	U_F	$I_F=1 A$		1.4	1.8	V
	U_{FP}	$I_{FP}=4 A^*$		2.4		
Total Radiated Power	P_o	$I_F=1 A$	140	210		mW
		$I_{FP}=4 A^*$		540		
Radiant Intensity	I_E	$I_F=1 A$		70		mW/sr
		$I_{FP}=4 A^*$		180		
Beam Angle	$2\theta_{1/2}$	$I_F=100 mA$		128		deg.
Rise Time	t_r	$I_F=1 A$		90		ns
Fall Time	t_f	$I_F=1 A$		30		ns

* duty cycle = 1 %, pulse width = 10 µs



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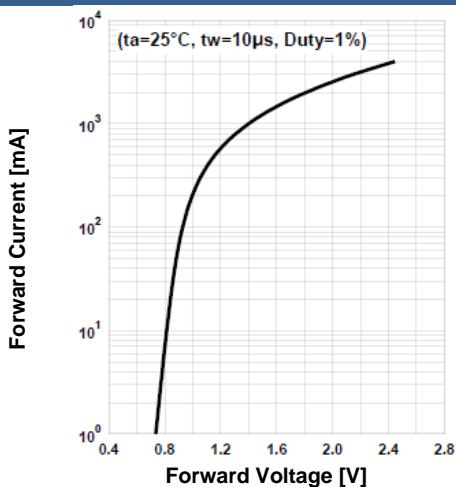
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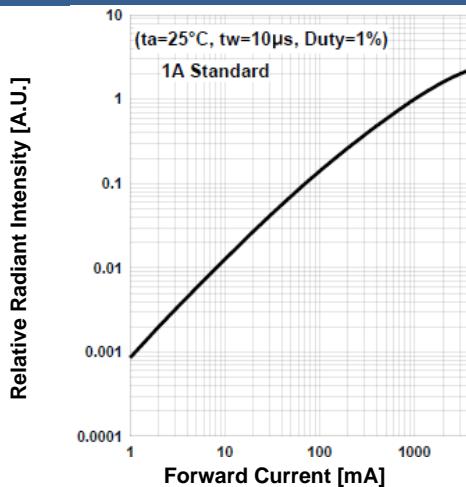


Typical Performance Curves

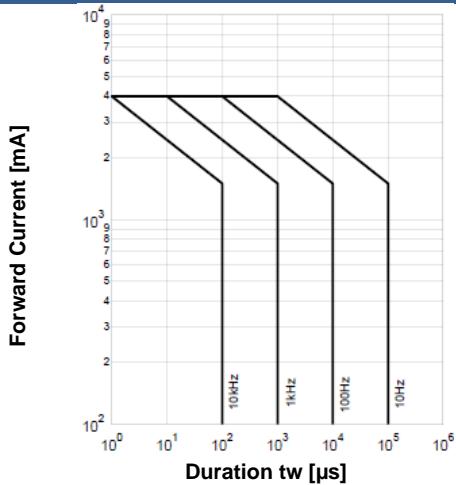
Forward Current vs. Forward Voltage



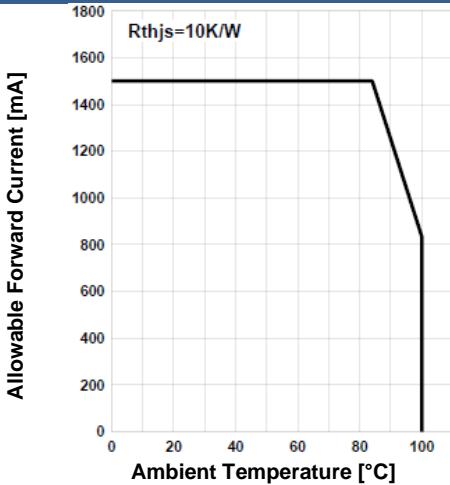
Relative Radiant Intensity vs. Forward Current



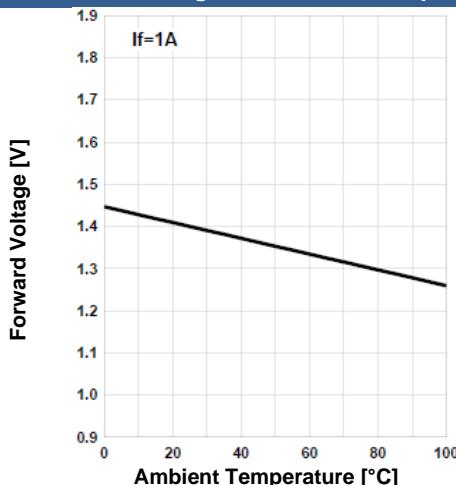
Forward Current vs. Pulse Duration



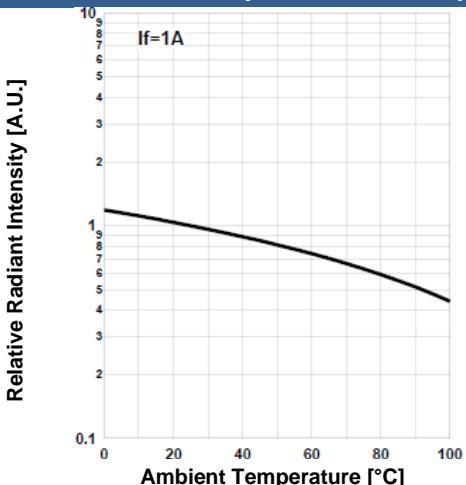
Allowed Forward Current vs. Amb. Temperature



Forward Voltage vs. Ambient Temperature



Rel. Radiant Intensity vs. Ambient Temperature





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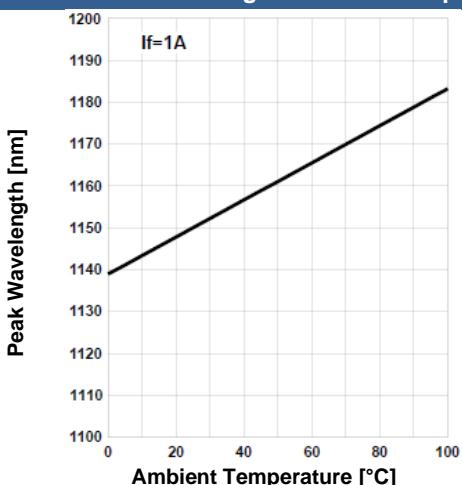
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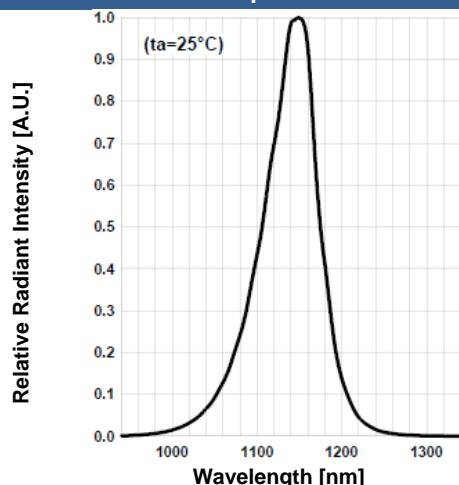


Typical Performance Curves

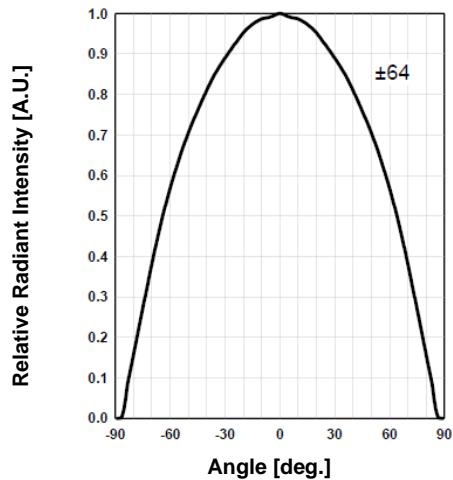
Peak Wavelength vs. Amb. Temp.



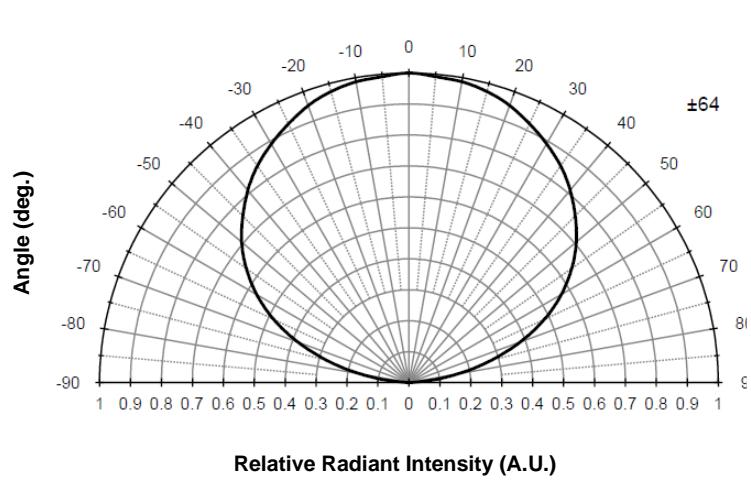
Relative Spectral Emission



Radiation Characteristics

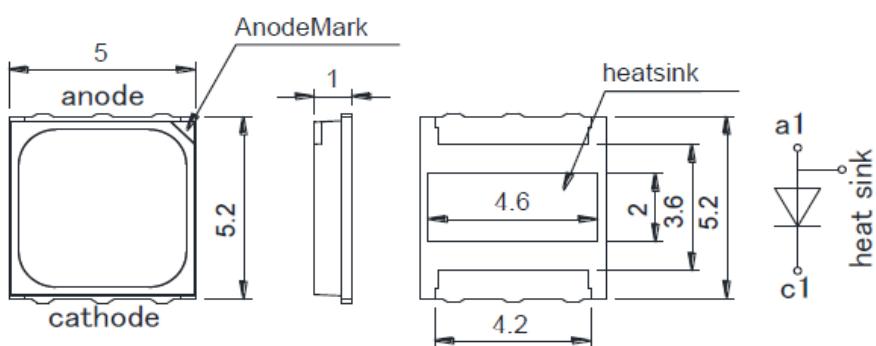


Radiation Characteristics



Outline Dimensions

PA9T



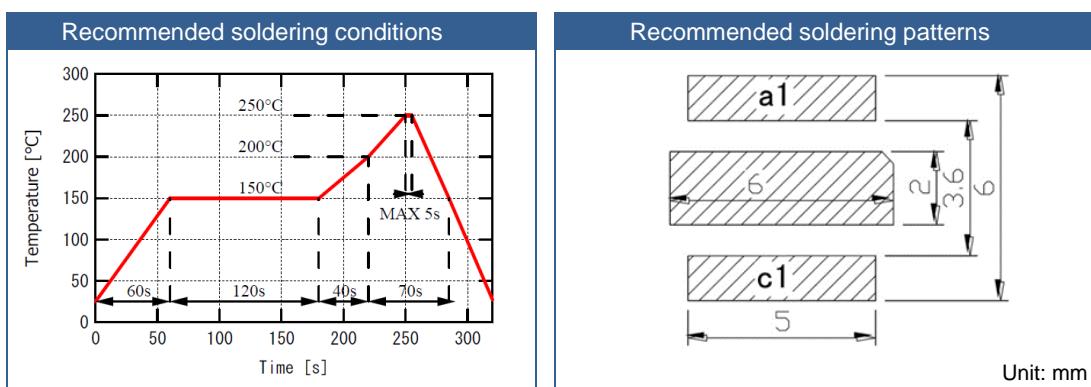
all dimensions in mm



General Notes

Soldering

- Do avoid overheating of the LED
- Do avoid electrostatic discharge (ESD)
- Do avoid mechanical stress, shock, and vibration
- Do only use non-corrosive flux
- Do not apply current to the LED until it has cooled down to room temperature after soldering



Cleaning

- Cleaning with isopropyl alcohol, propanol, or ethyl alcohol is recommended
- DO NOT USE acetone, chloroform, trichloroethylene, or MKS
- DO NOT USE ultrasonic cleaners

Static Electricity

- LEDs are sensitive to electrostatic discharge (ESD).
- Precautions against ESD must be taken when handling or operating these LEDs
- Surge voltage or electrostatic discharge can result in complete failure of the LED.

Radiation

- During operation these LEDs do emit light, which could be hazardous to skin and eyes, and may cause cancer.
- Do avoid exposure to the emitted light. Protective glasses if needed
- It is further advised to attach a warning label on products/systems.

Operation

- Do only operate LEDs with a current source.
- Running these LEDs from a voltage source will result in complete failure of the device.
- Current of a LED is an exponential function of the voltage across it. Usage of current regulated drive circuits is mandatory.

Storage

- The maximum shelf life of LEDs in the originally sealed aluminum bag is 12 months.
- Before opening the aluminum bag, please store it at <30 °C, <60 % RH.
- After opening the aluminum bag, please solder the LEDs within 72 hours (floor life) at 5 – 30 °C, <50 % RH.
- Put any unused, remaining LEDs and silica gel back in the same aluminum bag and then vacuum-seal the bag.
- It is recommended to keep the re-sealed bag in a desiccator at <30%RH.